

PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1
 Stylesheet Version v1.2

EPAS ID: PAT5287708

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT
CONVEYING PARTY DATA	
Name	Execution Date
CHE-CHENG CHANG	07/28/2015
CHIH-HAN LIN	07/28/2015
JR-JUNG LIN	07/28/2015
RECEIVING PARTY DATA	
Name:	TAIWAN SEMICONDUCTOR MANUFACTURING COMPANY, LTD.
Street Address:	8, LI-HSIN RD. 6
Internal Address:	HSINCHU SCIENCE PARK
City:	HSINCHU
State/Country:	TAIWAN
Postal Code:	300-78
PROPERTY NUMBERS Total: 1	
Property Type	Number
Application Number:	16222837
CORRESPONDENCE DATA	
Fax Number:	(214)200-0853
<i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i>	
Phone:	214-651-5000
Email:	ipdocketing@haynesboone.com
Correspondent Name:	HAYNES AND BOONE, LLP IP SECTION
Address Line 1:	2323 VICTORY AVENUE
Address Line 2:	SUITE 700
Address Line 4:	DALLAS, TEXAS 75219
ATTORNEY DOCKET NUMBER:	2014-1067/24061.3053US04
NAME OF SUBMITTER:	LINDA INGRAM
SIGNATURE:	/Linda Ingram/
DATE SIGNED:	12/17/2018
Total Attachments: 2	
source=3053US04_Assignment#page1.tif	
source=3053US04_Assignment#page2.tif	

Docket No.: P20141067US01/24061.3053
Customer No.: 000042717

ASSIGNMENT

WHEREAS, we,

- (1) Che-Cheng Chang of Taiwan 300-77, Republic of China
- (2) Chih-Han Lin of Taiwan 300-77, Republic of China
- (3) Jr-Jung Lin of Taiwan 300-77, Republic of China

have invented certain improvements in

METHOD AND STRUCTURE FOR FINFET ISOLATION

for which we have executed an application for Letters Patent of the United States of America,

_____ of even date filed herewith; and
X filed on 12-22-2014 and assigned application number 14/579,728; and

WHEREAS, we authorize the attorney of record to update this document to include Patent Office information as deemed necessary (i.e., filing date, serial number, etc.);

WHEREAS, Taiwan Semiconductor Manufacturing Company, Ltd., ("TSMC"), No. 8, Li-Hsin Rd. 6, Science-Based Industrial Park Hsin-Chu, Taiwan 300-77, Republic of China, is desirous of obtaining the entire right, title, and interest in, to and under the said invention and the said application in the United States of America and in any and all countries foreign thereto;

NOW, THEREFORE, for good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, and other good and valuable consideration, we have sold, assigned, transferred and set over, and by these presents do hereby sell, assign, transfer and set over, unto the said TSMC, its successors, legal representatives, and assigns, the entire right, title, and interest in, to and under the said invention, and the said application, and all divisional, renewal, substitutional, and continuing applications thereof, and all Letters Patent of the United States of America which may be granted thereon and all reissues and extensions thereof, and all applications for Letters Patent which may be filed for said invention in any country or countries foreign to the United States of America, and all extensions, renewals, and reissues thereof, and all prior patents and patent applications from which a filing priority of the above-described patent application may be obtained, including the right to collect past damages; and we hereby authorize and request the Commissioner of Patents of the United States of America, and any official of any country or countries foreign to the United States of America, whose duty it is to issue patents on applications as aforesaid, to issue all Letters Patent for said invention to the said TSMC, its successors, legal representatives and assigns, in accordance with the terms of this instrument.

AND WE HEREBY covenant that we have full right to convey the entire interest herein assigned, and that we have not executed, and will not execute, any agreement in conflict herewith.

AND WE HEREBY further covenant and agree that we will communicate to said TSMC, its successors, legal representatives and assigns, any facts known to us respecting said invention, and testify in any legal proceedings, sign all lawful papers, execute all divisional, renewal, substitutional, continuing, and reissue applications, make all rightful declarations and/or oaths and generally do everything possible to aid the said TSMC, its successors, legal representatives and assigns, to obtain and enforce proper patent protection for said invention in all countries.

Docket No.: P20141067US01/24061.3053
Customer No.: 000042717

Inventor Name: Che-Cheng Chang

Residence Address: No. 8, Li-Hsin Rd. 6, Science-Based Industrial Park
Hsin-Chu 300-77, Taiwan, R.O.C.

Dated: 2015/7/28

Che-Cheng Chang
Inventor Signature

Inventor Name: Chih-Han Lin

Residence Address: No. 8, Li-Hsin Rd. 6, Science-Based Industrial Park
Hsin-Chu 300-77, Taiwan, R.O.C.

Dated: 2015/7/28

Chih-Han Lin
Inventor Signature

Inventor Name: Jr-Jung Lin

Residence Address: No. 8, Li-Hsin Rd. 6, Science-Based Industrial Park
Hsin-Chu 300-77, Taiwan, R.O.C.

Dated: 2015/7/28

Jr-Jung Lin
Inventor Signature